

DEC

SBR520 THRU SBR5100

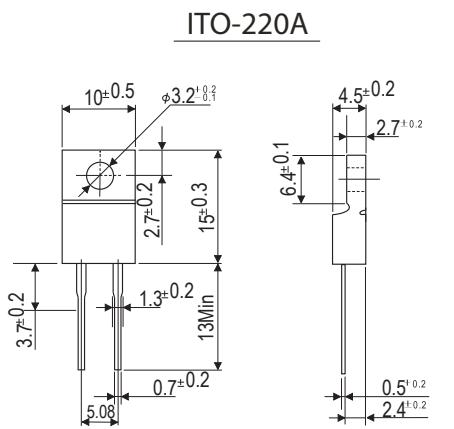
CURRENT 5.0Amperes
VOLTAGE 20 to 100 Volts

Features

- Plastic Package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction, majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss, high efficiency
- High current capability, Low forward voltage drop
- Single rectifier construction
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- High temperature soldering guaranteed:
250 °C/10 seconds, 0.25" (6.35mm) from case

Mechanical Data

- Case : JEDEC ITO-220A molded plastic body
- Terminals : Lead solderable per MIL-STD-750, Method 2026
- Polarity : As marked
- Mounting Position : Any
- Weight : 0.08 ounce, 2.24 grams



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

(Ratings at 25 °C ambient temperature unless otherwise specified, single phase, half wave, resistive or inductive load. For capacitive load, derate by 20%)

	Symbols	SBR 520	SBR 530	SBR 540	SBR 560	SBR 580	SBR 590	SBR 5100	Units
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	60	80	90	100	Volts
Maximum RMS voltage	V _{RMS}	14	21	28	42	56	63	70	Volts
Maximum DC blocking voltage	V _{DC}	20	30	40	60	80	90	100	Volts
Maximum average forward rectified current (see Fig. 1)	I _(AV)					5.0			Amps
Repetitive peak forward current(square wavr, 20KHZ) at T _c =105 °C	I _{FRM}					10.0			Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}					100.0			Amps
Maximum instantaneous forward voltage at 5.0A (Note 1)	V _F			0.55	0.70		0.85		Volts
Maximum instantaneous reverse current at rated DC blocking voltage (Note1)	T _A =25 °C	I _R				1.0			mA
	T _A =125 °C			15			50		
Typical thermal resistance (Note 2)	R _{θJC}				5.0				°C/W
Operating junction temperature range	T _J		-65 to +125			-65 to +150			°C
Storage temperature range	T _{STG}				-65 to +150				°C

Notes:

- (1) Pulse test: 300 μS pulse width, 1% duty cycle
- (2) Thermal resistance from junction to case

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RATINGS AND CHARACTERISTIC CURVES SBR520-SBR5100

FIG. 1 - FORWARD CURRENT DERATING CURVE

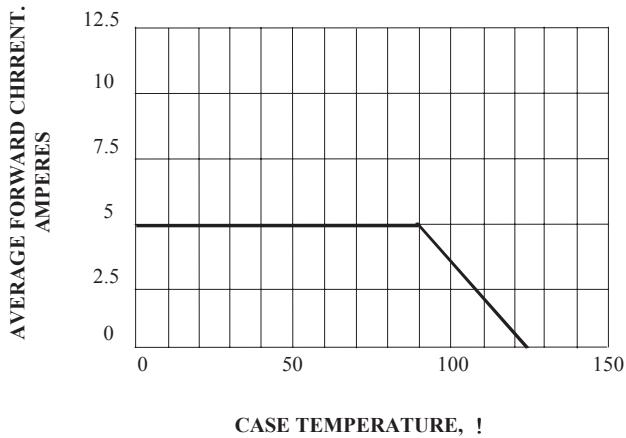


FIG. 2 - MAXIMUM NON-REPETITIVE SURGE CURRENT

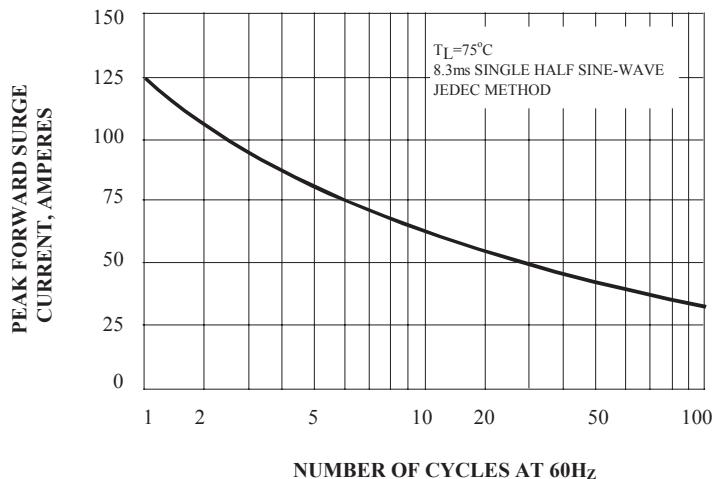


FIG. 3 - TYPICAL REVERSE CHARACTERISTICS

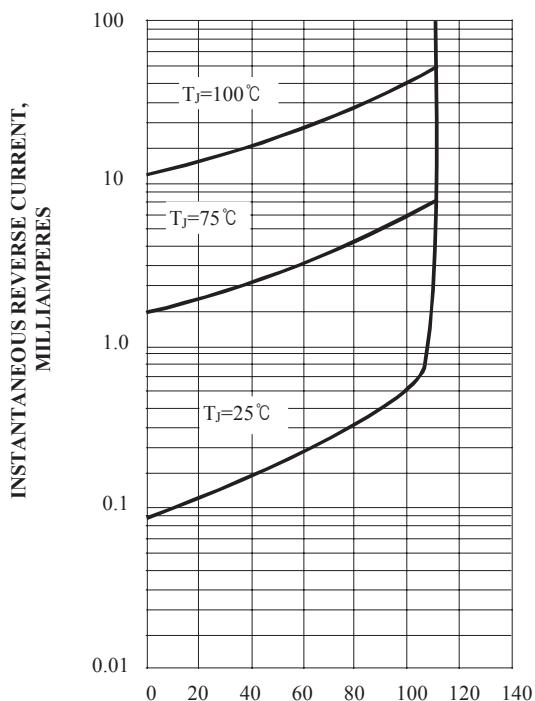
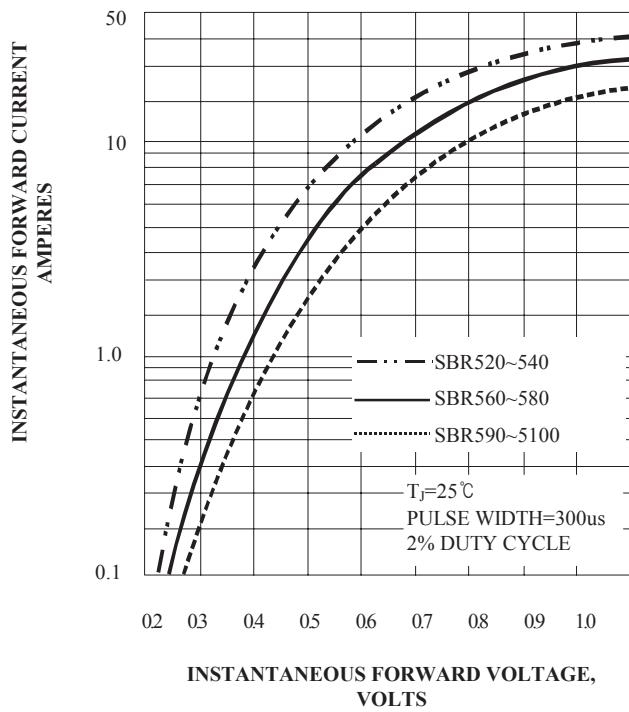


FIG. 4 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



PERCENT OR RATED VOLTAGE PEAK
REVERSE VOLTAGE